ATTENUATOR CHIP 10 WATT



EN 13-3506

DATA SHEET

PART SERIES: 83-7014-XX.XX

APPLICATIONS

Mobile Networks

High Power Amplifiers

Isolators/Circulators

Instrumentation

Broadcast

Military

FEATURES

Small Footprint High Power Surface Mount Low VSWR Easy Installation Wide Attenuation Offering

GENERAL DESCRIPTION

EMC Technology offers the widest selection of chip attenuators worldwide. Chip components are offered in Alumina, Aluminum Nitride, Beryllium Oxide, and CVD diamond for maximum performance.

ORDERING INFORMATION

Part Identifier:

83-7014-<u>XX.XX</u>

Attenuation Value

SPECIFICATIONS

1.0 ELECTRICAL

Nominal Impedance:	50 ohms
Frequency Range:	DC - 3 GHz
Attenuation Values Available:	20 - 30 dB
Attenuation Accuracy:	20 dB ±0.5 dB
	21 - 30 dB ±1.5 dB
Input Power CW:	10 watts @ 100°C heat sink, derated linearly to zero power at 150° C
Peak Power:	100 watts (based on 10us pulse width and 1% duty cycle)
VSWR:	20 dB 1.25:1 Max
	21 - 30dB 1.30:1 Max

2.0 ENVIRONMENTAL

Operating Temperature:	-55°C to +150°C
Non-operating Temperature:	-65°C to +150°C
Temperature Coefficient:	+/-200 PPM / °C max

3.0 MARKING

Unit Marking:

None

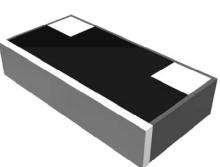
4.0 QUALITY ASSURANCE

Sample Inspect Per MIL-STD-105, Level II, 1.0% AQL. Visual and Mechanical Inspection for Conformance to Outline Drawing Measure Attenuation and VSWR Data Retention - Standard

5.0 PACKAGING

Standard Packaging:

Tape and Reel



Dwg 82-7014

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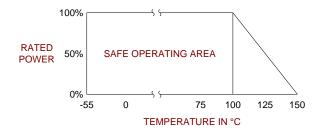
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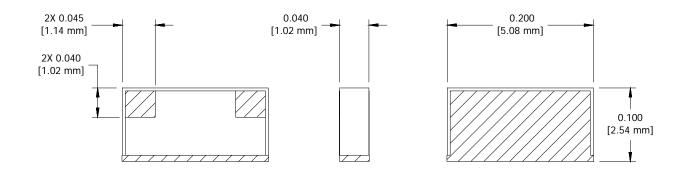
Dwg 82-7014

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6.0 MECHANICAL

Substrate Material: Resistive Film: Terminal Material: Metric Dimensions: Aluminum Nitride Thin Film Thick film, Tin/Lead plated Provided for reference only





Unless Otherwise Specified: TOLERANCE: X.XX = ± 0.02 X.XXX = ± 0.010